DESCRIPTION

The BAS40W/-04/-05/-06 is available in SOT-323 package.

APPLICATION

- Case: SOT-323, Molded Plastic
- Case Material-UL Flammability Rating Classification 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020A
- Thermals: Solderable per MIL-STD-20, Method
 208
- Weight: 0.006 grams (approx.)

APPLICATION

- Low Forward Voltage Drop
- Fast Switching
- Ultra-Small Surface Mount Package
- PN Junction Guard Ring for Transient and ESD Protection

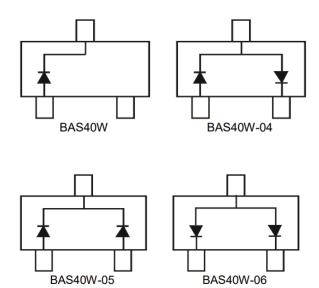
PIN DESCRIPTION



SOT-323

ORDERING INFORMATION

Package Type	Part Number		
SOT-323	BAS40W		
	BAS40W-04		
	BAS40W-05		
	BAS40W-06		
SPQ	3,000pcs/Reel		
AiT provides all RoHS Compliant Products			



ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise specified.

V _{RRM} , Peak Repetitive Revere Voltage	40V	
V _{RWM} , Working Peak Reverse Voltage	40V	
V _{RRM} , DC Blocking Voltage	40V	
V _{R(RMS)} , RMS Reverse Voltage	28V	
I _{FM} , Forward Continuous Current	200mA	
I _{FSM} , Non-Repetitive Peak Forward Continuous Current	t = 1.0 s	600mA
P _d , Power Dissipation	200mW	
R _{0JA} , Thermal Resistance Junction to Ambient Air *	625°C/W	
T _J , Operating Temperature Range	-55°C ~ + 125°C	
T _{STG} , Storage Temperature Range	-65°C ∼ + 150°C	

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

T_A=25°C unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Reverse Breakdown Voltage	$V_{(BR)R}$	I _R =10μA	40	-	-	V
Forward Voltage	VF	I _F =1mA, t _p < 300μs	-	-	380	mV
		I _F =40mA, t _p < 300μs	-	-	1000	
Leakage Current	I _R	V _R = 30V	-	-	200	nA
Total Capacitance	Ст	V _R = 0, f=1.0MHz	-	-	5	pF
Reverse Recovery Time	t _{rr}	$I_F = I_R = 10 \text{mA}, I_{rr} = 0.1 \text{ x } I_R,$ $R_L = 100 \Omega$	-	-	5	ns

TYPICAL CHARACTERISTICS

Fig 1. Typical Forward Voltage

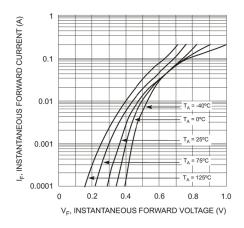


Fig 3. Typical Capacitance

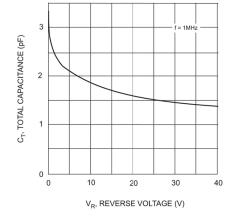


Fig 2. Typical Reverse Characteristics

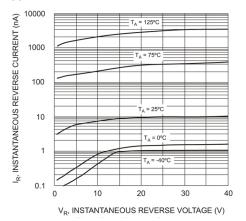
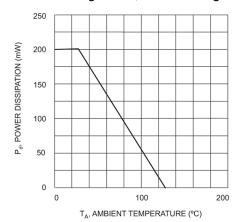
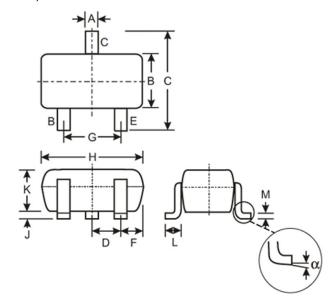


Fig 4. Power Derating Curve, Total Package



PACKAGE INFORMATION

Dimension in SOT-323 (Unit: mm)



SYMBOL	MILLIMETERS			
STWBOL	Min.	Max.		
А	0.250	0.400		
В	1.150	1.350		
С	2.000	2.200		
D	0.650 TYP.			
E	0.300	0.400		
G	1.200	1.400		
Н	1.800	2.200		
J	0.000	0.100		
K	0.900	1.000		
L	0.250	0.400		
М	0.100	0.180		
α	0°	8°		

BAS40W/-04/-05/-06
DIODE
SCHOTTKY BARRIER DIODE

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